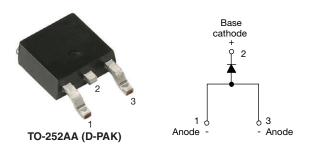
VS-8EWF..SPbF Soft Recovery Series

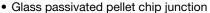
Vishay Semiconductors

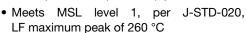
Surface Mount Fast Soft Recovery Rectifier Diode, 8 A



PRODUCT SUMMARY							
Package	TO-252AA (D-PAK)						
I _{F(AV)}	8 A						
V _R	1000 V, 1200 V						
V _F at I _F	1.3 V						
I _{FSM}	150 A						
t _{rr}	80 ns						
T _J max.	150 °C						
Diode variation	Single die						
Snap factor	0.6						

FEATURES







 Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

RoHS COMPLIANT

APPLICATIONS

- Output rectification and freewheeling diode in inverters, choppers and converters
- Input rectifications where severe restrictions on conducted EMI should be met

DESCRIPTION

The VS-8EWF..S-M3 fast soft recovery rectifier series has been optimized for combined short reverse recovery time, low forward voltage drop and low leakage current.

The glass passivation ensures stable reliable operation in the most severe temperature and power cycling conditions.

MAJOR RATINGS AND CHARACTERISTICS										
SYMBOL	CHARACTERISTICS	VALUES	UNITS							
I _{F(AV)}	Sinusoidal waveform	8	A							
V _{RRM}		1000/1200	V							
I _{FSM}		150	А							
V _F	8 A, T _J = 25 °C	1.3	V							
t _{rr}	1 A, 100 A/μs	80	ns							
TJ	Range	-40 to +150	°C							

VOLTAGE RATINGS			
PART NUMBER	V _{RRM} , MAXIMUM PEAK REVERSE VOLTAGE V	V _{RSM} , MAXIMUM NON-REPETITIVE PEAK REVERSE VOLTAGE V	I _{RRM} AT 150 °C mA
VS-8EWF10SPbF	1000	1100	4
VS-8EWF12SPbF	1200	1300	4

ABSOLUTE MAXIMUM RATINGS									
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS					
Maximum average forward current	I _{F(AV)}	T _C = 94 °C, 180° conduction half sine wave	8						
Maximum peak one cycle	I _{FSM}	10 ms sine pulse, rated V _{RRM} applied 125		Α					
non-repetitive surge current		10 ms sine pulse, no voltage reapplied	150						
Maximum I ² t for fusing	l ² t	10 ms sine pulse, rated V _{RRM} applied 78		A ² s					
Maximum i-t for fusing		0 ms sine pulse, no voltage reapplied 110							
Maximum I ² √t for fusing	I²√t	t = 0.1 to 10 ms, no voltage reapplied	1100	A²√s					



VS-8EWF..SPbF Soft Recovery Series

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ELECTRICAL SPECIFICATIONS									
PARAMETER	SYMBOL	TEST COI	VALUES	UNITS					
Maximum forward voltage drop	V_{FM}	8 A, T _J = 25 °C	1.3	V					
Forward slope resistance	r _t	T _{.1} = 150 °C	25.6	mΩ					
Threshold voltage	V _{F(TO)}	1j = 150 C	0.93	V					
Maximum rayoraa laakaga aurrant	1	T _J = 25 °C	V _B = Rated V _{BBM}	0.1	mΛ				
Maximum reverse leakage current	IRM	T _J = 150 °C	VR = hateu VRRM	4	mA				

RECOVERY CHARACTERISTICS									
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS	· •				
Reverse recovery time	t _{rr}	In at 8 And	270	ns	I _{FM} t				
Reverse recovery current	I _{rr}	I _F at 8 A _{pk} 25 Α/μs	4.2	Α	$t_a \mid t_b$				
Reverse recovery charge	Q _{rr}	T _J = 25 °C	1	μC	di / Q _{rr}				
Snap factor	S		0.6		V I _{rr}				

THERMAL - MECHANICAL SPECIFICATIONS									
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS					
Maximum junction and storage temperature range	T _J , T _{Stg}		-40 to +150	°C					
Maximum thermal resistance, junction to case	R _{thJC}	DC operation	2.5	°C ///					
Typical thermal resistance, junction to ambient (PCB mount)	R _{thJA} (1)		50	°C/W					
Approximate weight			1	g					
Approximate weight			0.03	OZ.					
Marking device		Case style TO-252AA (D-PAK)	8EWF	-12S					

Note

⁽¹⁾ When mounted on 1" square (650 mm²) PCB of FR-4 or G-10 material 4 oz. (140 µm) copper 40 °C/W For recommended footprint and soldering techniques refer to application note #AN-994

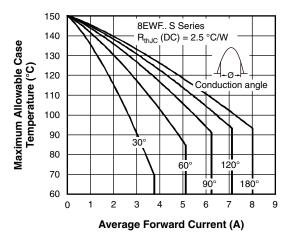


Fig. 1 - Current Rating Characteristics

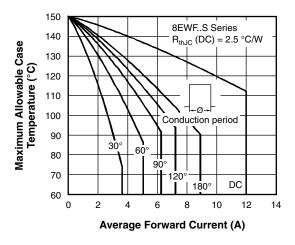


Fig. 2 - Current Rating Characteristics

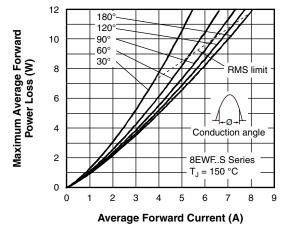


Fig. 3 - Forward Power Loss Characteristics

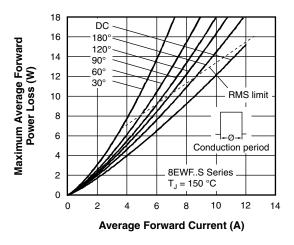


Fig. 4 - Forward Power Loss Characteristics

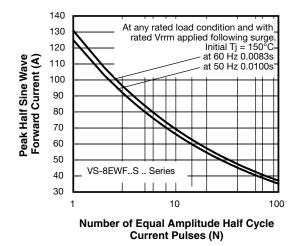


Fig. 5 - Maximum Non-Repetitive Surge Current

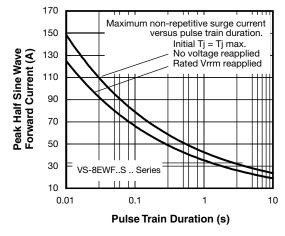


Fig. 6 - Maximum Non-Repetitive Surge Current

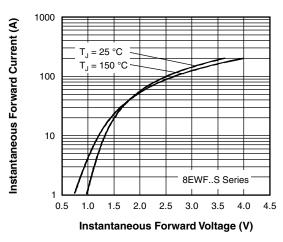


Fig. 7 - Forward Voltage Drop Characteristics

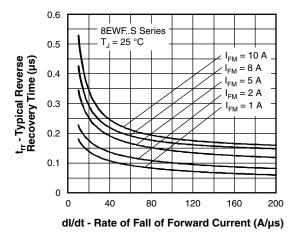


Fig. 8 - Recovery Time Characteristics, $T_J = 25$ °C

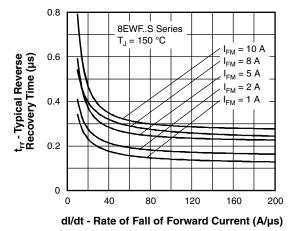


Fig. 9 - Recovery Time Characteristics, T_J = 150 °C

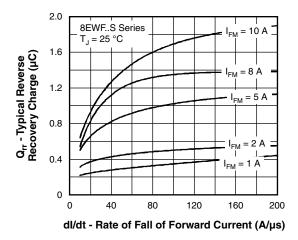


Fig. 10 - Recovery Charge Characteristics, T_J = 25 °C

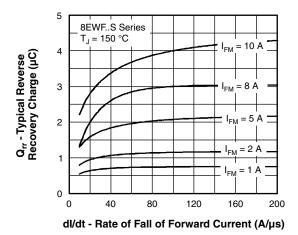
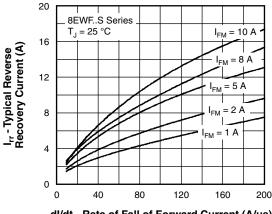


Fig. 11 - Recovery Charge Characteristics, T_J = 150 °C



dl/dt - Rate of Fall of Forward Current (A/ μ s)

Fig. 12 - Recovery Current Characteristics, T_J = 25 °C

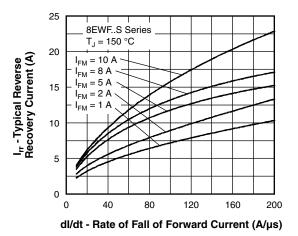


Fig. 13 - Recovery Current Characteristics, T_J = 150 °C

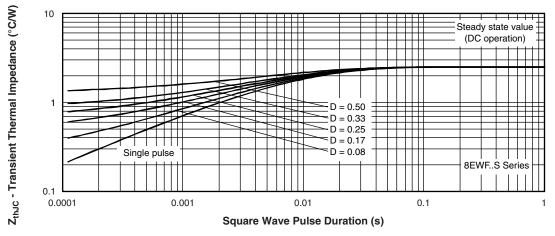


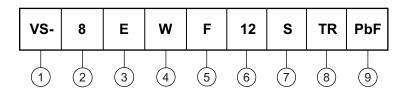
Fig. 14 - Thermal Impedance Z_{thJC} Characteristics

VS-8EWF..SPbF Soft Recovery Series

Vishay Semiconductors

ORDERING INFORMATION TABLE

Device code



1 - Vishay Semiconductors product

2 - Current rating (8 = 8 A)

Circuit configuration:

E = single diode

4 - Package:

W = D-PAK

5 - Type of silicon:

F = fast soft recovery rectifier

Voltage code x 100 = V_{RRM} —

10 = 1000 V 12 = 1200 V

7 - S = surface mountable

- • TR = tape and reel

• TRR = tape and reel (right oriented)

• TRL = tape and reel (left oriented)

9 - None = standard production

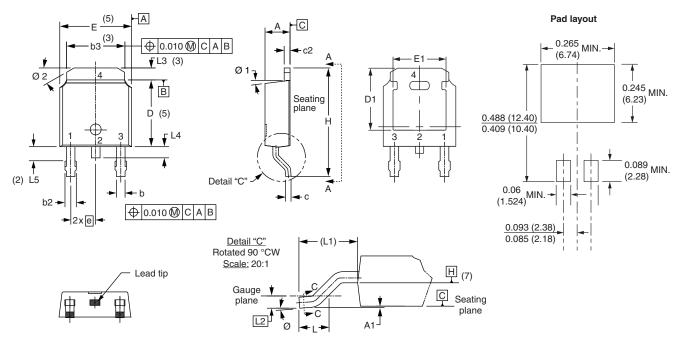
• PbF = lead (Pb)-free

LINKS TO RELATED DOCUMENTS							
Dimensions	www.vishay.com/doc?95016						
Part marking information	www.vishay.com/doc?95059						
Packaging information	www.vishay.com/doc?95033						
SPICE model	www.vishay.com/doc?95552						



D-PAK (TO-252AA)

DIMENSIONS in millimeters and inches



CVMDOL	MILLIN	LIMETERS		INCHES			CVMDOL	MILLIM	IETERS	INC	HES	NOTES
SYMBOL	MIN.	MAX.	MIN.	MAX.	NOTES	OTES	SYMBOL	MIN.	MAX.	MIN.	MAX.	NOTES
Α	2.18	2.39	0.086	0.094			е	2.29	BSC	0.090	BSC	
A1	-	0.13	-	0.005			Н	9.40	10.41	0.370	0.410	
b	0.64	0.89	0.025	0.035			L	1.40	1.78	0.055	0.070	
b2	0.76	1.14	0.030	0.045			L1	2.74	BSC	0.108	REF.	
b3	4.95	5.46	0.195	0.215	3		L2	0.51	BSC	0.020	BSC	
С	0.46	0.61	0.018	0.024			L3	0.89	1.27	0.035	0.050	3
c2	0.46	0.89	0.018	0.035			L4	-	1.02	-	0.040	
D	5.97	6.22	0.235	0.245	5		L5	1.14	1.52	0.045	0.060	2
D1	5.21	-	0.205	-	3		Ø	0°	10°	0°	10°	
Е	6.35	6.73	0.250	0.265	5		Ø1	0°	15°	0°	15°	
E1	4.32	-	0.170	-	3		Ø2	25°	35°	25°	35°	

Notes

- (1) Dimensioning and tolerancing as per ASME Y14.5M-1994
- (2) Lead dimension uncontrolled in L5
- (3) Dimension D1, E1, L3 and b3 establish a minimum mounting surface for thermal pad
- (4) Section C C dimension apply to the flat section of the lead between 0.13 and 0.25 mm (0.005 and 0.10") from the lead tip
- (5) Dimension D, and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outermost extremes of the plastic body
- (6) Dimension b1 and c1 applied to base metal only
- (7) Datum A and B to be determined at datum plane H
- (8) Outline conforms to JEDEC outline TO-252AA



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